

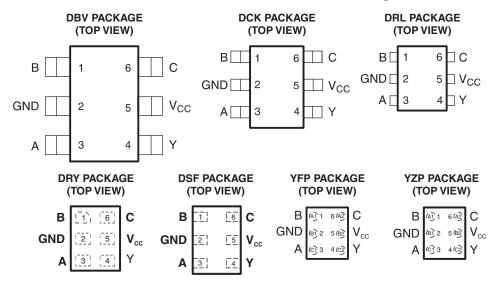
LOW-POWER CONFIGURABLE MULTIPLE-FUNCTION GATE

Check for Samples: SN74AUP1G98

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Max)
- Low Dynamic-Power Consumption (C_{pd} = 4.6 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Includes Schmitt-Trigger Inputs

- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $t_{pd} = 5.3 \text{ ns Max at } 3.3 \text{ V}$
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

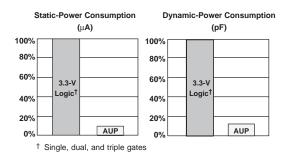
The SN74AUP1G98 features configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and noninverter. All inputs can be connected to V_{CC} or GND.

The device functions as an independent gate with Schmitt-trigger inputs, which allow for slow input transition and better switching-noise immunity at the input.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





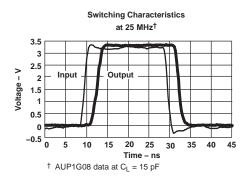


Figure 1. AUP - The Lowest-Power Family

Figure 2. Excellent Signal Integrity

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAGE ⁽²⁾		PACKAGE(2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾		
	NanoStar – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP1G98YFPR	HR_				
	NanoStar – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G98YZPR	HR_				
-40°C to 85°C	QFN – DRY	Reel of 5000	SN74AUP1G98DRYR	HR				
10 0 10 00 0	uQFN – DSF	Reel of 5000	SN74AUP1G98DSFR	HR				
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1G98DBVR	H98_				
	SOT (SC-70) - DCK	Reel of 3000	SN74AUP1G98DCKR	G G				
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUP1G98DRLR	- HR_				

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

FUNCTION TABLE

	INPUTS		OUTPUT
С	В	Α	Υ
L	L	L	H
L	L	Н	Н
L	Н	L	L
L	Н	Н	L
Н	L	L	Н
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	L

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⁽³⁾ DBV/DCK/DRL: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, ● = Pb-free).



LOGIC DIAGRAM (POSITIVE LOGIC)

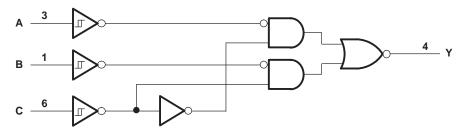


Table 1. FUNCTION SELECTION TABLE

LOGIC FUNCTION	FIGURE NO.
2-to-1 data selector with inverted output	Figure 3
2-input NAND gate	Figure 4
2-input NOR gate with one inverted input	Figure 5
2-input AND gate with one inverted input	Figure 5
2-input NAND gate with one inverted input	Figure 6
2-input OR gate with one inverted input	Figure 6
2-input NOR gate	Figure 7
Noninverted buffer	Figure 8
Inverter	Figure 9

LOGIC CONFIGURATIONS

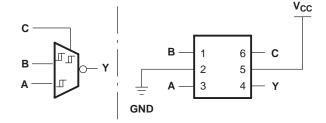


Figure 3. 2-to-1 Data Selector With Inverted Output When C is L, Y = $\frac{\overline{B}}{A}$ When C is H, Y = \overline{A}

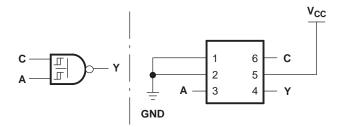


Figure 4. 2-Input NAND Gate



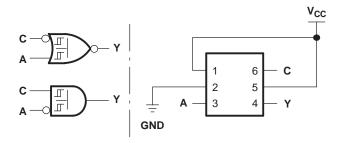


Figure 5. 2-Input NOR Gate With One Inverted Input 2-Input AND Gate With One Inverted Input

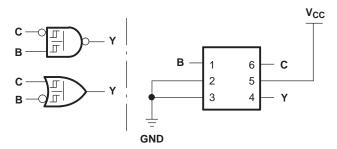


Figure 6. 2-Input NAND Gate With One Inverted Input 2-Input OR Gate With One Inverted Input

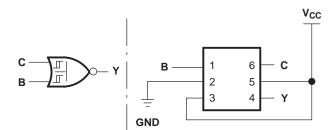


Figure 7. 2-Input NOR Gate

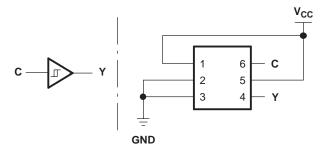


Figure 8. Noninverted Buffer



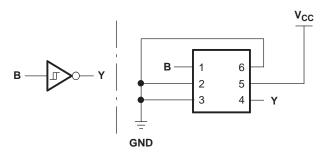


Figure 9. Inverter



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range ⁽²⁾		-0.5	4.6	V	
Vo	Voltage range applied to any output in the h	nigh-impedance or power-off state (2)	-0.5	4.6	V	
Vo	Output voltage range in the high or low stat	e ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
lok	Output clamp current	V _O < 0		-50	mA	
lo	Continuous output current			±20	mA	
	Continuous current through V _{CC} or GND			±50	mA	
		DBV package		165		
		DCK package		259		
0	Declines the resulting adapted (3)	DRL package		142	00/14/	
θ_{JA}	Package thermal impedance (3)	DSF package		300	°C/W	
		DRY package		234		
		YFP/YZP package		123		
T _{stg}	Storage temperature range		-65		°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V_{CC}	Supply voltage		0.8	3.6	V	
V_{I}	Input voltage		0	3.6	V	
Vo	Output voltage		0	V _{CC}	V	
		V _{CC} = 0.8 V		-20	Α	
		V _{CC} = 1.1 V		-1.1		
	High-level output current	V _{CC} = 1.4 V		-1.7	ı	
I _{OH}		V _{CC} = 1.65		-1.9	mA	
		V _{CC} = 2.3 V		-3.1	ı	
		V _{CC} = 3 V		-4	ı	
		V _{CC} = 0.8 V		20	μΑ	
		V _{CC} = 1.1 V		1.1		
	Low lovel output ourrent	V _{CC} = 1.4 V		1.7		
I _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA	
		V _{CC} = 2.3 V		3.1	ı	
		V _{CC} = 3 V		4		
T_A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	Т,	_A = 25°C	$T_A = -40^{\circ}C$ to	85°C	UNIT	
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MAX	MIN	MAX	UNII	
V_{T+}		0.8 V	0.3	0.6	0.3	0.6		
		1.1 V	0.53	0.9	0.53	0.9		
Positive-going		1.4 V	0.74	1.11	0.74	1.11	V	
input threshold		1.65 V	0.91	1.29	0.91	1.29	V	
voltage		2.3 V	1.37	1.77	1.37	1.77		
		3 V	1.88	2.29	1.88	2.29		
V _T		0.8 V	0.1	0.6	0.1	0.6		
		1.1 V	0.26	0.65	0.26	0.65		
Negative-going		1.4 V	0.39	0.75	0.39	0.75	\ /	
input threshold		1.65 V	0.47	0.84	0.47	0.84	V	
voltage		2.3 V	0.69	1.04	0.69	1.04		
		3 V	0.88	1.24	0.88	1.24		
ΔV_{T}		0.8 V	0.07	0.5	0.07	0.5		
		1.1 V	0.08	0.46	0.08	0.46		
		1.4 V	0.18	0.56	0.18	0.56	.,	
Hysteresis		1.65 V	0.27	0.66	0.27	0.66	V	
$(V_{T+} - V_{T-})$		2.3 V	0.53	0.92	0.53	0.92		
		3 V	0.79	1.31	0.79	1.31		
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1			
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		0.7 × V _{CC}			
	I _{OH} = -1.7 mA	1.4 V	1.11		1.03			
	$I_{OH} = -1.9 \text{ mA}$	1.65 V	1.32		1.3		V	
V _{OH}	$I_{OH} = -2.3 \text{ mA}$		2.05		1.97			
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85			
	$I_{OH} = -2.7 \text{ mA}$		2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1		0.1		
	I _{OL} = 1.1 mA	1.1 V		0.3 × V _{CC}	0.	.3 × V _{CC}		
	I _{OL} = 1.7 mA	1.4 V		0.31		0.37		
	I _{OL} = 1.9 mA	1.65 V		0.31		0.35		
V_{OL}	I _{OL} = 2.3 mA			0.31		0.33	V	
	I _{OL} = 3.1 mA	2.3 V		0.44		0.45		
	I _{OL} = 2.7 mA			0.31		0.33		
	I _{OL} = 4 mA	3 V		0.44		0.45		
I _I All inputs	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V		0.1		0.5	μΑ	
I _{off}	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V}$	0 V		0.2		0.6	<u>.</u> μΑ	
ΔI _{off}	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.6	<u>.</u> μΑ	
I _{cc}	$V_I = \text{GND or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V		0.5		0.9	μA	
ΔI _{CC}	$V_I = V_{CC} - 0.6 V^{(1)}, I_O = 0$	3.3 V		40		50	μА	
		0 V		1.5				
C _i	$V_I = V_{CC}$ or GND	3.6 V		1.5			pF	
C _o	V _O = GND	0 V		3			pF	

⁽¹⁾ One input at V_{CC} – 0.6 V, other inputs at V_{CC} or GND.



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 pF$ (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	T	_{\(\)} = 25°C		T _A = -		UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
		Y	0.8 V		22.2				
	A, B, or C		1.2 V ± 0.1 V	2.7	9.1	13.6	2.2	17	
			1.5 V ± 0.1 V	2	6.4	9.2	1.5	11.1	
t _{pd}			1.8 V ± 0.15 V	1.4	5.2	7.2	0.9	8.9	ns
			2.5 V ± 0.2 V	1.2	3.8	5.3	0.7	6.3	
			3.3 V ± 0.3 V	1	3.1	4.5	0.5	5.3	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 10 pF (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM	TO	V _{CC}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
		Y	0.8 V		25.4				
	A, B, or C		1.2 V ± 0.1 V	5.2	10.4	15.4	4.7	19	
			1.5 V ± 0.1 V	4	7.4	10.5	3.5	12.6	
t _{pd}			1.8 V ± 0.15 V	3.1	6	8.3	2.6	10.2	ns
			2.5 V ± 0.2 V	2.7	4.5	6.1	2.2	7.3	
			3.3 V ± 0.3 V	2.5	3.7	5	2	6	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM (INPUT) (O	TO (OUTPUT)	TO (OUTPUT) V _{CC}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
		(001701)		MIN	TYP	MAX	MIN	MAX	
		Y	0.8 V		28.7				
	A, B, or C		1.2 V ± 0.1 V	3.7	11.5	17	3.2	21.1	
			1.5 V ± 0.1 V	2.8	8.3	11.6	2.3	14	
t _{pd}			1.8 V ± 0.15 V	2.1	6.7	9.2	1.6	11.3	ns
			2.5 V ± 0.2 V	1.8	5	6.7	1.3	8.1	
			3.3 V ± 0.3 V	1.6	4.1	5.5	1.1	6.6	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	PARAMETER FROM TO (OUTPUT)	_	V	T _A = 25°C			T _A = -40°C to 85°C		UNIT
			MIN	TYP	MAX	MIN	MAX		
		Y	0.8 V		39.7				
	A, B, or C		1.2 V ± 0.1 V	5.1	15.3	21.6	4.6	26.8	
			1.5 V ± 0.1 V	3.9	10.9	14.6	3.4	17.6	
t _{pd}			1.8 V ± 0.15 V	3.1	8.9	11.5	2.6	14.1	ns
			2.5 V ± 0.2 V	2.6	6.7	8.4	2.1	10.1	
			3.3 V ± 0.3 V	2.3	5.5	6.9	1.8	8.3	

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OPERATING CHARACTERISTICS

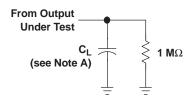
 $T_A = 25^{\circ}C$

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	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
			1.2 V ± 0.1 V	4	pF
_	Dower discipation conscitons	f 40 MH=	1.5 V ± 0.1 V	4	
C _{pd}	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V	4	
			2.5 V ± 0.2 V	4.3	
			3.3 V ± 0.3 V	4.6	

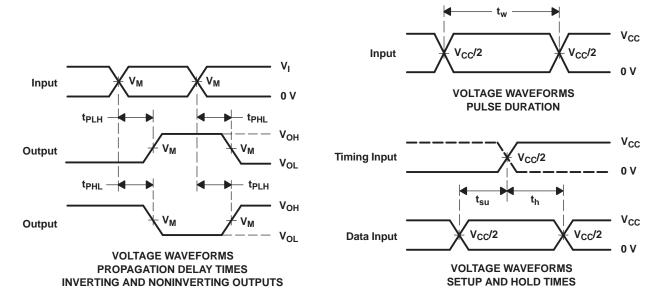


PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Duration)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}



NOTES: A. C_L includes probe and jig capacitance.

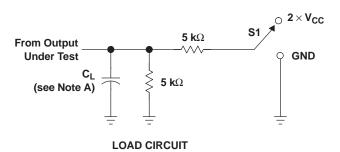
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, slew rate \geq 1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd}.
- E. All parameters and waveforms are not applicable to all devices.

Figure 10. Load Circuit and Voltage Waveforms

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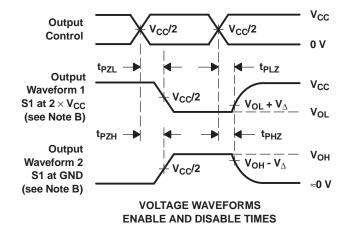


PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S 1
t _{PLZ} /t _{PZL}	$2 \times V_{CC}$
t _{PHZ} /t _{PZH}	GND

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _∆	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

LOW- AND HIGH-LEVEL ENABLING

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. All parameters and waveforms are not applicable to all devices.

Figure 11. Load Circuit and Voltage Waveforms

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24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74AUP1G98DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DBVTE4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H98R	Samples
SN74AUP1G98DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HRR	Samples
SN74AUP1G98DRLR	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HR7, HRR)	Samples
SN74AUP1G98DRLRG4	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HR7, HRR)	Samples
SN74AUP1G98DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HR	Samples
SN74AUP1G98DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HR	Samples
SN74AUP1G98YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(HR7, HRN)	Samples



PACKAGE OPTION ADDENDUM

24-Jan-2013

Orderable Device	Status	Package Type	_	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
SN74AUP1G98YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(HR7, HRN)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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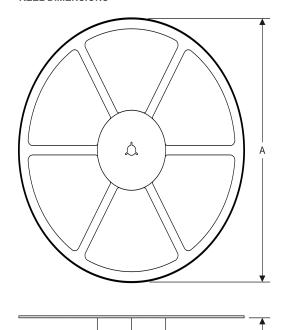
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PACKAGE MATERIALS INFORMATION

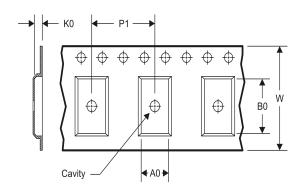
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter	Reel Width	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
					(mm)	W1 (mm)						
SN74AUP1G98DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G98DBVT	SOT-23	DBV	6	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G98DCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
SN74AUP1G98DCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
SN74AUP1G98DRLR	SOT	DRL	6	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G98DRLR	SOT	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G98DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G98DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G98YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1G98YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G98DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74AUP1G98DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74AUP1G98DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74AUP1G98DCKT	SC70	DCK	6	250	202.0	201.0	28.0
SN74AUP1G98DRLR	SOT	DRL	6	4000	180.0	180.0	30.0
SN74AUP1G98DRLR	SOT	DRL	6	4000	202.0	201.0	28.0
SN74AUP1G98DRYR	SON	DRY	6	5000	180.0	180.0	30.0
SN74AUP1G98DSFR	SON	DSF	6	5000	180.0	180.0	30.0
SN74AUP1G98YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0
SN74AUP1G98YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



DRL (R-PDSO-N6)

PLASTIC SMALL OUTLINE



NOTES:

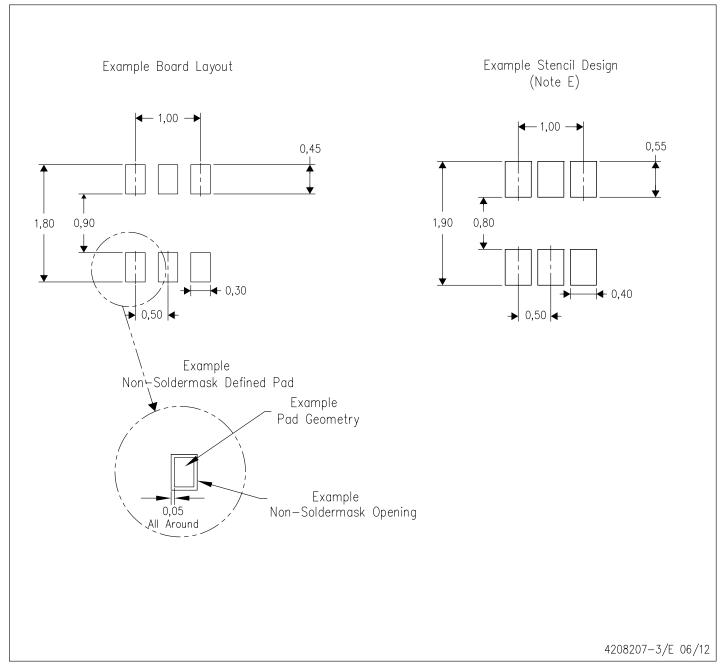
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



DRL (R-PDSO-N6)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- $frac{f}{K}$ See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.





NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
 C. SON (Small Outline No-Lead) package configuration.
 D. This package complies to JEDEC MO-287 variation X2AAF.





PLASTIC SMALL OUTLINE NO-LEAD



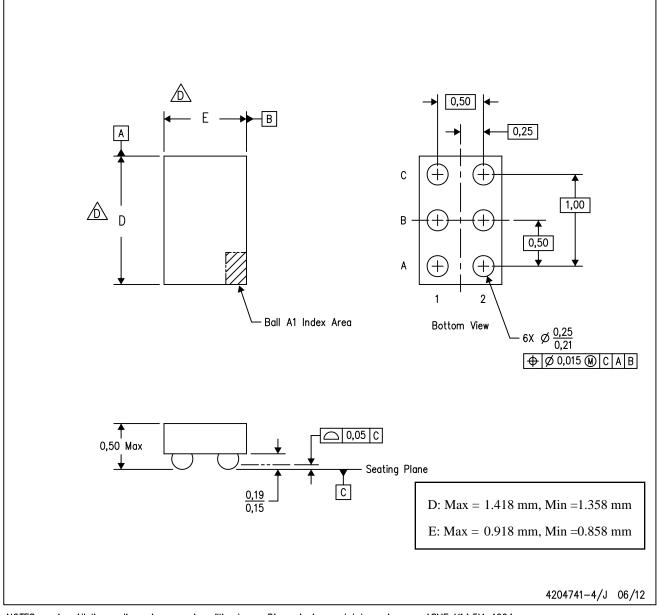
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

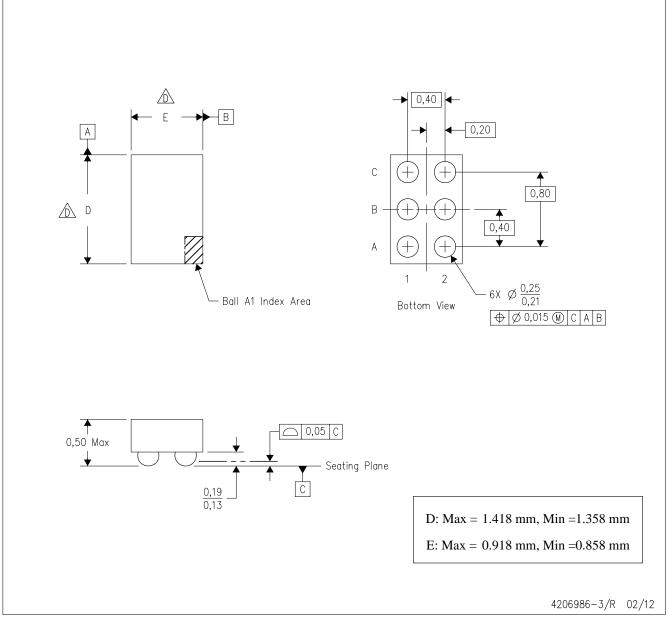
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
- E. This package is a Pb-free solder ball design. Refer to the 6 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.

- E. Reference Product Data Sheet for array population. 2 x 3 matrix pattern is shown for illustration only.
- F. This package contains Pb-free balls.

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